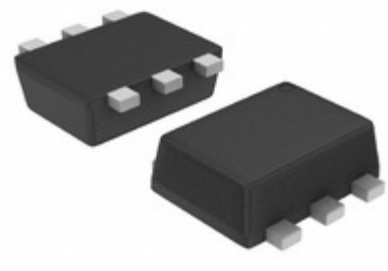







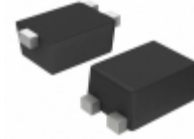

	<h2 style="color: red;">NSBC114EPDXV6T1G</h2>	
	Hersteller-Teilenummer:	NSBC114EPDXV6T1G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	TRANS PREBIAS NPN/PNP SOT563
	Datenblätter:	 NSBC114EPDXV6T1G.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 50193 pcs Stock Available.
	Liefern von:	Hong Kong
Image may be representation. See specs for product details.	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	NSBC114EPDXV6T1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN/PNP SOT563
Kategorie	Diskrete Halbleiterprodukte > Transistoren-bipolare
Teilstatus	50193 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SOT-563
Transistor-Typ	1 NPN, 1 PNP - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	35 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	10k
Widerstand - Emitter-Basis (R2) (Ohm)	10k
Verpackung	Tape & Reel (TR)

NSBC114EPDXV6T1G ist neu im Original, Suche NSBC114EPDXV6T1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSBC114EPDXV6T1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSBC114EPDXV6T1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NSBC114EDXV6T1G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>	 <p>NSBC114EPDXV6T5 ON NSBC114EPDXV6T5 ON</p>	 <p>NSBC114EPDXV6T1 AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p>NSBC114TDXV6T1G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>
 <p>NSBC114EDXV6T5G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>	 <p>NSBC114EPDXV6T5G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p>NSBC114EF3T5G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 254MW SOT1123</p>	 <p>NSBC114TDP6T5G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.339W SOT963</p>

heiße Teile

Mehr

⊕ 06036C104KAT2A	↔ AM4915P-T1-PF	⇒ FMC6AT148	D JE-112DM	↔ LT3970IMS#TRPBF
⊖ LTC1373CS8	⊕ MAX4800ACQI+	D MG75H2YL1	⇒ NSB1706DMW5T1G	↔ NSB4904DW1T1G
⊕ NSB8JT-E3/31	⊖ NSB9435T1	⊕ NSB9435T1G	↔ NSBA114EDP6T5G	↔ NSBA114EDXV6T1
D NSBA114YDXV6T1	⊕ NSBA123JDXV6T1	⊖ NSBA123JDXV6T1G	⊕ NSBA123JDXV6T5G	↔ NSBA143TDXV6T1G
⇒ NSBA144EDP6T5G	↔ NSBC114EDXV6T1	⊕ NSBC114EDXV6T1G	⊖ NSBC114EPDXV6T5	↔ NSBC114TDXV6T1
↔ NSBC114YDP6T5G	⇒ NSBC114YDXV6T1	D NSBC114YDXV6T1G	⊕ NSBC114YDXV6T5	⊖ NSBC114YPDXV6T1
⊕ NSBC115EDXV6T1	D NSBC123JDXV6T1	⇒ NSBC123JPDV6T1	↔ NSBC123JPDV6T1G	↔ NSBC124EPDXV6T1
⊖ NSBC124EPDXV6T5	⊕ NSBC124XPDXV6T1	↔ NSBC143EDXV6T5	⇒ NSBC143ZPDV6T1G	↔ NSBC143ZPDV6T5
⊕ NSBC144EDXV6T1	⊖ NSBC144EDXV6T1G	⊕ NSBC144EDXV6T5	D NSBC144EDXV6T5G	↔ NSBC144EPDXV6T1
↔ NSBC144EPDXV6T1G	⊕ PIC16LC642-04/SO	⊖ SAF-C868P-1SRBA	⊕ UCC27512DRSR	↔ VLF3012AT-4R7MR7

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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